



查询CMBTH10供应商

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

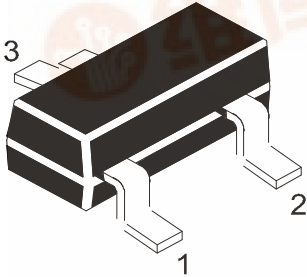
捷多邦，专业PCB打样工厂，24小时加急出货



NPN SILICON PLANAR EPITAXIAL TRANSISTOR

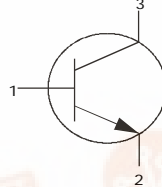
CMBTH10

SOT-23
Formed SMD Package



PIN CONFIGURATION (NPN)

- 1 = BASE
- 2 = EMITTER
- 3 = COLLECTOR



Marking Code = 3E

VHF/UHF Transistor

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Emitter Voltage	V_{CEO}	25	V
Collector Base Voltage	V_{CBO}	30	V
Emitter Base Voltage	V_{EBO}	3.0	V

THERMAL CHARACTERISTICS

*Device Dissipation FR-5 Board, $T_a=25^{\circ}\text{C}$ Derate above $=25^{\circ}\text{C}$	P_D	225 1.8	mW mW/ $^{\circ}\text{C}$
Thermal Resistance Junction to Ambient in free Air	$R_{th(j-a)}$	556	$^{\circ}\text{C}/\text{mW}$
**Device Dissipation Alumina Substrate, $T_a=25^{\circ}\text{C}$ Derate above $=25^{\circ}\text{C}$	P_D	300 2.4	mW mW/ $^{\circ}\text{C}$
Thermal Resistance Junction to Ambient in free Air	$R_{th(j-a)}$	417	$^{\circ}\text{C}/\text{mW}$
Junction and Storage Temperature	T_j, T_{stg}	150	$^{\circ}\text{C}$

* FR-5 Board=25.4 x 19.05 x 1.58 mm (1.0 x 0.75 x 0.062 inches)

** Alumina Substrate=10.16 x 7.62 x 0.61 mm (0.4 x 0.3 x 0.024 inches) 99.5% alumina.

Electrical Characteristics ($T_a=25^{\circ}\text{C}$ unless specified otherwise)

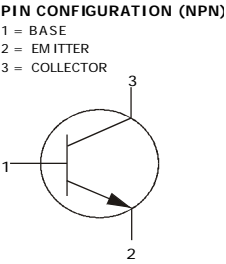
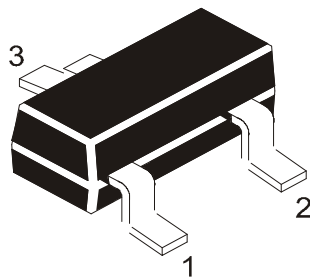
DESCRIPTION	SYMBOL	CONDITIONS	MIN	MAX	UNIT
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	25		V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$	30		V
Emitter Base Voltage	V_{EBO}	$I_E=10\mu\text{A}, I_C=0$	3		V
Collector Cut Off Current	I_{CBO}	$V_{CB}=25\text{V}, I_E=0$		100	nA
Emitter Cut Off Current	I_{EBO}	$V_{EB}=2\text{V}, I_C=0$		100	nA
DC Current Gain	h_{FE}	$V_{CE}=10\text{V}, I_C=4\text{mA}$	60		
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=4\text{mA}, I_B=0.4\text{mA}$		0.50	V
Base Emitter On Voltage	$V_{BE(on)}$	$V_{CE}=10\text{V}, I_C=4\text{mA}$		0.95	V



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Electrical Characterstics (T_a=25°C unless specified otherwise)

DYNAMIC CHARACTERISTICS

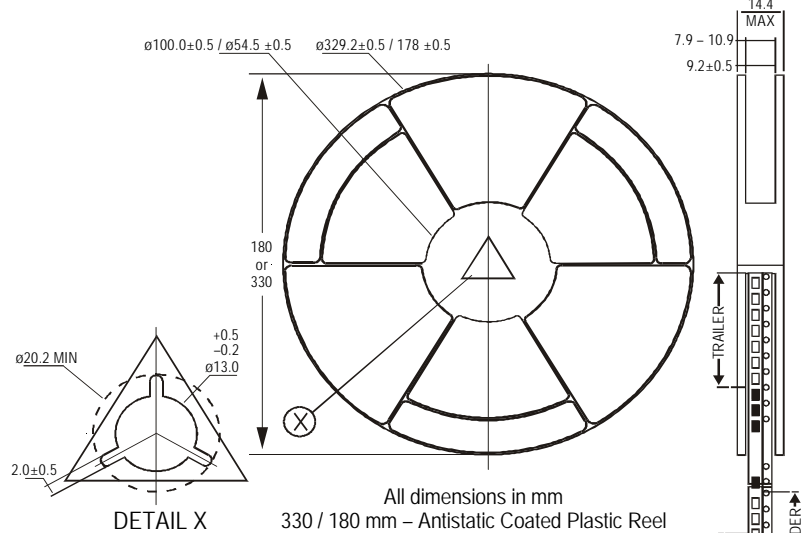
DESCRIPTION	SYMBOL	CONDITIONS	MIN	MAX	UNIT
Current Gain - Bandwidth Product	f _T	V _{CE} =10V, I _C =4mA, f=100MHz	650		MHz
Collector Base Capacitance	C _{cb}	V _{CB} =10V, I _E =0, f=1MHz		0.70	pF
Common Base Feedback Capacitance	C _{rb}	V _{CB} =10V, I _E =0, f=1MHz		0.65	pF
Collector Base Time Constant	rb' C _c	V _{CB} =10V, I _c =4mA, f=31.8MHz		9.0	ps

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SOT-23 Package Reel Information

Reel Specifications for W Packing (13") and 7"



NOTES:	8mm Tape Size of Reel	8mm Tape Size of Reel	
	No. of Devices	No. of Devices	
	330 mm (13")	180 mm (7")	
	10,000 Pcs	3,000 Pcs	
1.	The bandolier of 330 mm reel contains at least 10,000 devices.		
2.	The bandolier of 180 mm reel contains at least 3,000 devices.		
3.	No more than 0.5% missing devices / reel. 50 empty compartments for 330 mm reel. 15 empty compartments for 180 mm reel.		
4.	Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.		
5.	The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.		

All dimensions in mm

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/feel	136 gm/3K pcs	3" x 7.5" x 7.5"	12 K	17" x 15" x 13.5"	192 K	12 kgs
			9" x 9" x 9"	51 K	19" x 19" x 19"	408 K	28 kgs
	10K/feel	415 gm/10K pcs	13" x 13" x 0.5"	10 K	17" x 15" x 13.5"	300 K	16 kgs

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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